



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

July 30, 2026

IGI Report Number

DESCRIPTION

Shape and Cutting Style

Measurements

LG799631510

LABORATORY GROWN DIAMOND

ROUND BRILLIANT

8.18 - 8.25 X 4.96 MM

GRADING RESULTS

Carat Weight

Color Grade

Clarity Grade

Cut Grade

2.04 CARATS

E

FLAWLESS

IDEAL

ADDITIONAL GRADING INFORMATION

Polish

Symmetry

Fluorescence

Inscription(s)

EXCELLENT

EXCELLENT

NONE

LG799631510

Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.
Type II

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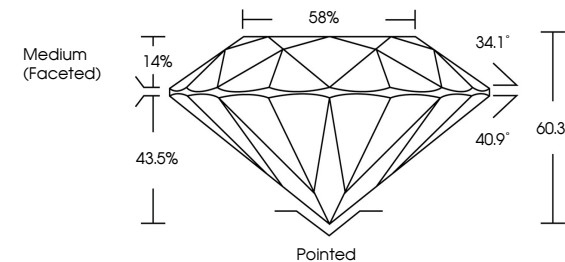
EXCELLENT

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PROPORTIONS



Medium (Faceted)

58%

34.1°

40.9°

60.3%

14%

43.5%

Pointed

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.

Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL IF VVS¹⁻² VS¹⁻² SI¹⁻² I¹⁻³

Flawless Internally Flawless Very Very Slightly Included Very Slightly Included Slightly Included Included

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